

NHPV08S600G, NHPJ08S600G

SWITCHMODE Power Rectifiers

Features

- Ultrafast 30 Nanosecond Recovery Time
- 150°C Operating Junction Temperature
- High Voltage Capability of 600 V
- Low Forward Drop
- Low Leakage Specified @ 125°C Case Temperature
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Mechanical Characteristics:

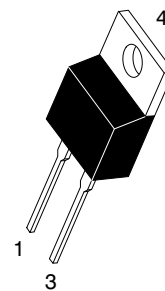
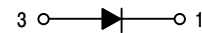
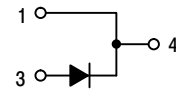
- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



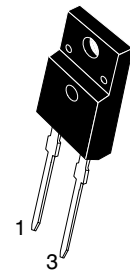
ON Semiconductor®

<http://onsemi.com>

PLANAR ULTRAFAST RECTIFIERS 8 A, 600 V

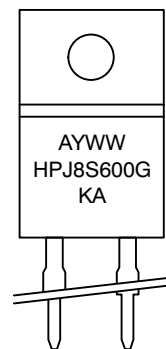


**TO-220AC
CASE 221B**



**TO-220 FULLPAK
CASE 221AG**

MARKING DIAGRAMS



- A = Assembly Location
- Y = Year
- WW = Work Week
- G = Pb-Free Package
- KA = Diode Polarity

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

NHPV08S600G, NHPJ08S600G

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	600	V
Average Rectified Forward Current (Rated V_R)	TO-220AC TO-220FP $I_{F(AV)}$	8 A @ $T_C = 130^\circ\text{C}$ 8 A @ $T_C = 95^\circ\text{C}$	A
Peak Rectified Forward Current (Rated V_R , Square Wave, 20 kHz)	TO-220AC TO-220FP I_{FRM}	8 A @ $T_C = 125^\circ\text{C}$ 8 A @ $T_C = 85^\circ\text{C}$	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I_{FSM}	80	A
Operating Junction Temperature and Storage Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
NHPV08S600G: Thermal Resistance Junction-to-Case (Note 1)	$R_{\theta JC}$	1.5	$^\circ\text{C}/\text{W}$
NHPJ08S600G: Thermal Resistance Junction-to-Case (Note 1)	$R_{\theta JC}$	4.25	$^\circ\text{C}/\text{W}$

1. Junction-to-Case shown as a typical value using a fixed 25°C cold plate boundary.

ELECTRICAL CHARACTERISTICS

Characteristic	Test Conditions	Symbol	Typ	Max	Unit
Instantaneous Forward Voltage (Note 2)	($I_F = 8\text{ A}, T_C = 125^\circ\text{C}$) ($I_F = 8\text{ A}, T_C = 25^\circ\text{C}$)	v_F	1.5 2.7	1.8 3.2	V
Instantaneous Reverse Current (Note 2)	(Rated DC Voltage, $T_C = 125^\circ\text{C}$) (Rated DC Voltage, $T_C = 25^\circ\text{C}$)	i_R	46 0.1	400 30	μA
Reverse Recovery Time	($I_F = 0.5\text{ A}, I_{rr} = 0.25\text{ A}, I_R = 1\text{ A}$) ($I_F = 1\text{ A}, di_F/dt = -50\text{ A}/\mu\text{s}, V_R = 30\text{ V}$)	t_{rr}	- -	30 50	ns
Reverse Recovery Time Peak Reverse Recovery Current Total Reverse Recovery Charge Softness Factor	($I_F = 8\text{ A}, di_F/dt = -200\text{ A}/\mu\text{s}, T_C = 25^\circ\text{C}$)	t_{rr} I_{RM} Q_{rr} S	30 2.3 37 2	50 3 50 -	ns A nC -
Reverse Recovery Time Peak Reverse Recovery Current Total Reverse Recovery Charge Softness Factor	($I_F = 8\text{ A}, di_F/dt = -200\text{ A}/\mu\text{s}, T_C = 125^\circ\text{C}$)	t_{rr} I_{RM} Q_{rr} S	45 5.5 150 0.35	- - - -	ns A nC -
Forward Recovery Time Forward Voltage Time	($I_F = 8\text{ A}, di_F/dt = 120\text{ A}/\mu\text{s}, T_C = 25^\circ\text{C}$)	t_{fr} V_{FP}	- -	200 6	ns V

2. Pulse Test: Pulse Width = 300 μs , Duty Cycle $\leq 2.0\%$.

ORDERING INFORMATION

Device	Package	Shipping [†]
NHPV08S600G	TO-220AC (Pb-Free / Halide-Free)	50 Units / Rail
NHPJ08S600G	TO-220FP (Pb-Free / Halide-Free)	50 Units / Rail

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL CHARACTERISTICS

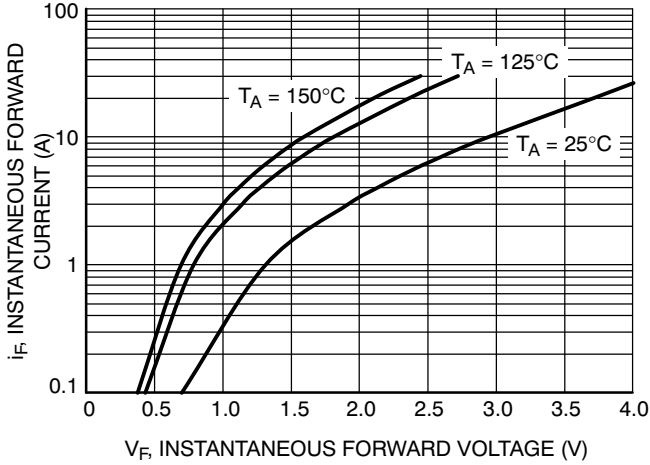


Figure 1. Typical Instantaneous Forward Characteristics

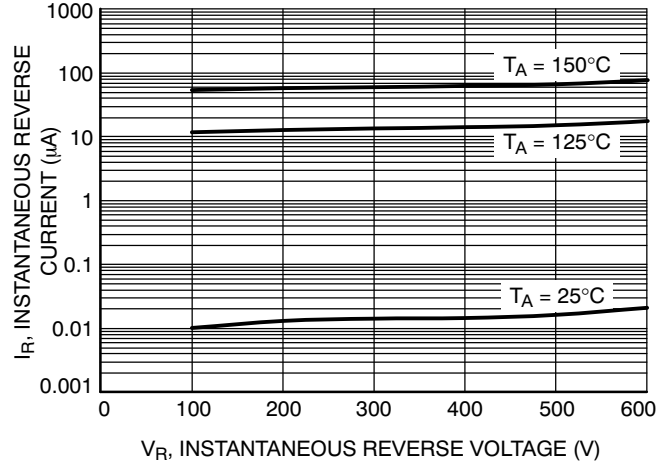


Figure 2. Typical Reverse Characteristics

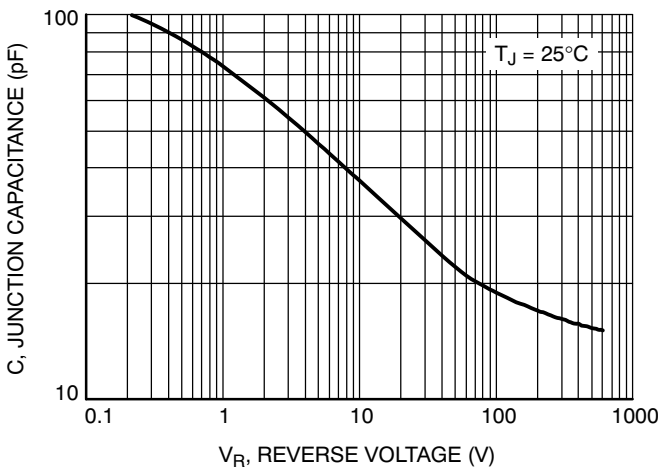


Figure 3. Typical Junction Capacitance

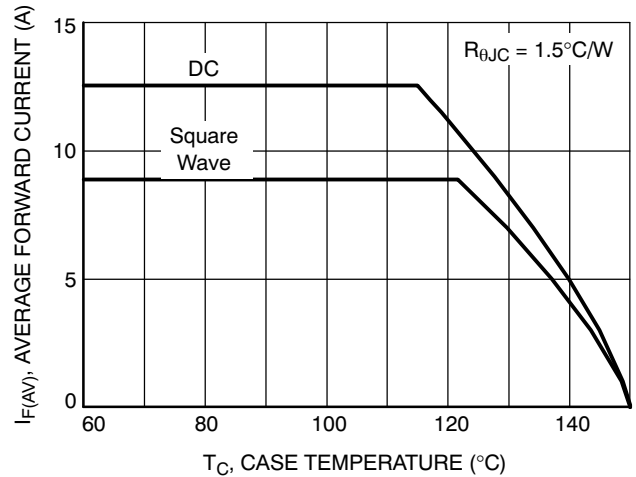


Figure 4. Current Derating TO-220AC

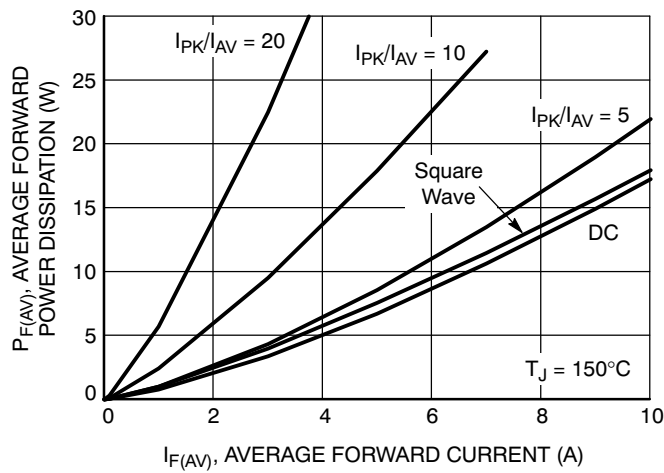
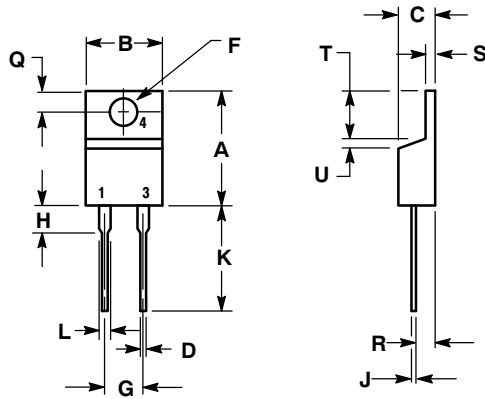


Figure 5. Forward Power Dissipation

NHPV08S600G, NHPJ08S600G

PACKAGE DIMENSIONS

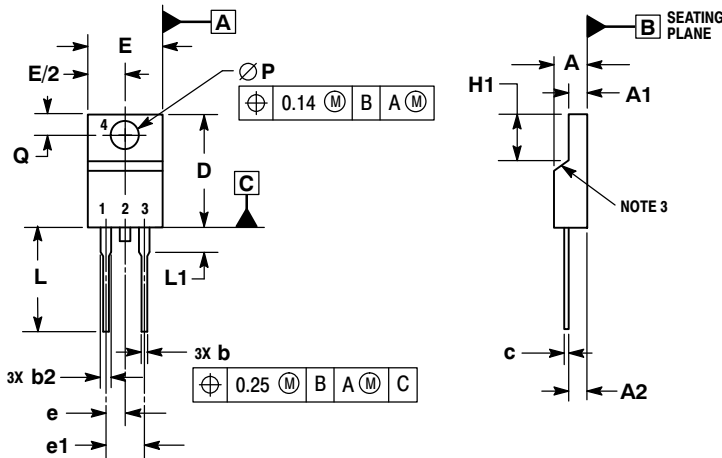
TO-220 TWO-LEAD CASE 221B-04 ISSUE E



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.595	0.620	15.11	15.75
B	0.380	0.405	9.65	10.29
C	0.160	0.190	4.06	4.82
D	0.025	0.035	0.64	0.89
F	0.142	0.161	3.61	4.09
G	0.190	0.210	4.83	5.33
H	0.110	0.130	2.79	3.30
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
T	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27

TO-220 FULLPAK, 2-LEAD CASE 221AG ISSUE O



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. CONTOUR UNCONTROLLED IN THIS AREA.
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH AND GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY.
 5. DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00.

DIM	MILLIMETERS	
	MIN	MAX
A	4.30	4.70
A1	2.50	2.90
A2	2.50	2.70
b	0.54	0.84
b2	1.10	1.40
c	0.49	0.79
D	14.22	15.88
E	9.65	10.67
e	2.54 BSC	
e1	5.08 BSC	
H1	5.97	6.48
L	12.70	14.73
L1	---	2.80
P	3.00	3.40
Q	2.80	3.20

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